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Theoretical treatments of ultrashort pulse laser processing of transparent materials: Towards explanations of extraordinary phenomena

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Laser beam propagation and plasma generation

Non-linear Schrödinger equation (NLSE)



$$\frac{\partial \overline{\boldsymbol{\mathcal{E}}}}{\partial z} = \frac{i}{2k_0} T^{-1} \left(\frac{\partial^2}{\partial r^2} + \frac{1}{r} \frac{\partial}{\partial r} \right) \overline{\boldsymbol{\mathcal{E}}} - \frac{ik''}{2} \frac{\partial^2 \overline{\boldsymbol{\mathcal{E}}}}{\partial t^2} + \frac{ik_0 n_2 T}{n_0} \left[(1 - f_R) \left| \overline{\boldsymbol{\mathcal{E}}} \right|^2 + f_R \int_{-\infty}^t R(t - \tau) \left| \overline{\boldsymbol{\mathcal{E}}} \right|^2 d\tau \right] \overline{\boldsymbol{\mathcal{E}}} - \frac{\sigma}{2} (1 + i\omega_0 \tau_c) T^{-1} (n_e \overline{\boldsymbol{\mathcal{E}}}) - \frac{1}{2} \frac{W_{\text{PI}} (\left| \overline{\boldsymbol{\mathcal{E}}} \right|) E_g}{\left| \overline{\boldsymbol{\mathcal{E}}} \right|^2} \overline{\boldsymbol{\mathcal{E}}}.$$

coupled with the rate equation for free carriers

$$\frac{\partial n_e}{\partial t} = \left[W_{PI}(\left|\overline{\boldsymbol{\mathcal{E}}}\right|) + \frac{On_e}{\left(1 + m_r / m_e\right)E_g} \left|\overline{\boldsymbol{\mathcal{E}}}\right|^2 \right] \frac{n_a}{n_l} - \frac{n_e}{t_{tr}}$$

NLSE is obtained from the Maxwell equations in assumption of UNIDIRECTIONAL beam propagation





Equation for the electric field accounting free carrier generation and associated processes

$$\frac{1}{c}\frac{\partial D}{\partial t} - i\frac{\omega}{c}D = -\frac{4\pi}{c}j + \operatorname{rot} H - \frac{8\pi e^2}{mc\omega^2}W_{PI0}\frac{\rho_a}{\rho_0}\left(\frac{|E^2|}{|E^2|}\right)^{\alpha-1}(1+E^2/(4E^2_*))E$$
$$\vec{E} = (\vec{E}_0 e^{-i\omega t} + \vec{E}_0^* e^{i\omega t})/2$$
$$D = E + \sum_m P_m + P_{nl} \qquad P_{nl} = \frac{c}{4\pi}n^2n_2\left((1-f_r)|E^2| + f_r\int_0^\infty R(\tau)|E^2(t-\tau)|d\tau\right)E$$

coupled with hydrodynamic model for free carriers

$$j = -\rho e \mathbf{V} \qquad \frac{\partial \rho}{\partial t} = W_{PI} + W_{\sigma} - \frac{\rho}{\tau_{tr}}$$
$$\frac{\partial (\rho \mathbf{V})}{\partial t} - i\omega\rho \mathbf{V} = -\rho \frac{e}{m_{e}} E - \rho \frac{\mathbf{V}}{\tau_{c}}$$

Free electron density inside fused silica Ti:sappire; 800 nm wavelength; beam waist 1 µm





Laser

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Snapshots of the laser beam intensity

Ti:sappire; 800 nm wavelength; beam waist 1 µm

 I_* is the critical intensity at which $\gamma = 1$



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What are the densities of free electrons under typical modification conditions?

 n_e^{max} values obtained numerically for single-pulse ultrafast laser excitation of silica glasses. Laser wavelength is 800 nm. $N_e^{cr} = 1.74 \times 10^{21} \text{ cm}^{-3}$

Pulse energy, μJ	Pulse duration, fs	NA	Material	Plasma density, cm ⁻³	Ref.
≥ 0.1	50	0.25	BK7	$\sim 1.7 \times 10^{20}$	D.M.Rayner et al. Opt. Exp., 13, 3208 (2005)
1.3	50	0.25	BK7	$\sim 7.5 \times 10^{20}$	Ibid
0.25-1.25	160	0.5	fused silica	$(4-6) \times 10^{20}$	A.Couairon, et al, <i>Phys. Rev. B</i> , 71 , 125435 (2005)
1	120	0.45	fused silica	~3×10 ²⁰	I.M.Burakov, et al., J. Appl. Phys., 101, 043506 (2007)
0.5	150	0.45	BK7	~5×10 ²⁰	A.Mermillod-Blondin, et al., <i>Phys. Rev. B</i> , 77 , 104205 (2008)
0.4	50	0.65	fused silica	$\sim 8 \times 10^{20}$	K.I. Popov, et al., Opt. Express, 19, 271 (2010)
1-2.5	50,80,150	0.25-0.36	fused silica	~6×10 ²⁰	Present study



Probe pulse

$$n_{e} = -\frac{\ln T \cdot \lambda}{4\pi L} \frac{2n_{0}\varepsilon_{0}\omega^{2}m_{e}^{*}}{e^{2}} \frac{1+\omega^{2}\tau_{c}^{2}}{\omega\tau_{c}}$$

D.G. Papazoglou, et al. *Opt. Lett.*, 32, 2055 (2007) $n_e \sim 4 \times 10^{19} \,\mathrm{cm^{-3}}$

M.C. Richardson, CLEO/QELS 2008, San Jose $n_e \sim 10^{17} - 10^{18} \text{ cm}^{-3}$



A possible solution can be in applying probe pulses whose frequency is smaller than ω_{pl} expected in the laser-excited region: For a 1560 nm femtosecond fiber laser (critical plasma density is ~4.6×10²⁰ cm⁻³), assuming that in fused silica $\tau_c \sim 10$ fs, the characteristic absorption length α_{ab}^{-1} is ~1 µm at $n_e = 8 \times 10^{20}$ cm⁻³ and $\alpha_{ab}^{-1} \sim 5$ µm at $n_e = 3.3 \times 10^{20}$ cm⁻³.

(Energ	by b	alanc	$c\rho(T$	$T^* - T_0) = n_e \left(E_e + E_g \right)$	
	т, = 350 К Т,	s 800 к 500 к 1 n _e [10	ublimation melting softening annealir	ng n ^{er} 10	I.M.Burakov, et al., J. Appl. Phys., 101, 043506 (20))07) J
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Energy - temperature - stress



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Comparing Maxwell and NLSE solutions 1 µJ, 150 fs, NA = 0.25



E_{ab} [J/cm³]

Comparing Maxwell and NLSE solutions

1 μJ, 50 fs, NA = 0.36



N.M. Bulgakova, V.P. Zhukov, M.P. Fedoruk, to be published

Nanogratings in transparent materials



Existing explanations: 1.Plasma wave interfering with optical beam Y. Shimotsuma et al. PRL, 91, 247405 (2003) 2. Nanoplasma self-ordering V. R. Bhardwaj et al. PRL, 96, 057404 (2006) 3. Exciton "self-organization"

M. Beresna et al., Appl. Phys. Lett., 101, 053120 (2012)

Key questions:

- 1. What is the actual mechanism?
- 2. Why do the nanogratings form only in several materials?
- 3. What are the main material properties for nanograting formation?

1. Plasma wave interfering with optical beam

Y. Shimotsuma et al. PRL, 91, 247405 (2003)





$$\Lambda = \frac{2\pi}{\sqrt{\frac{1}{T_e}(\frac{m_e\omega^2}{3k_B} - \frac{e^2N_e}{3\varepsilon_0k_B}) - k_{\rm ph}^2}}$$

Additionally, energy balance estimate

$$c\rho(T^* - T_0) = n_e \left(\frac{3}{2}kT_e + eE_g\right)$$

with near-critical plasma density and temperatures of order of 10⁶ K and higher gives huge lattice temperatures which would definitely result in microexplosion

Alternative could be the Tonk-Dattner resonances

L. Tonks, Phys. Rev. 37, 1458 (1931);

A. Dattner, Ericsson Technics No.2, Stockholm, 310 (1957)



$$\omega_j^2 = \omega_p^2 + (3kT/m_e)k_j^2, \quad j = 1, 2, 3, \dots$$

The multiple absorption and reflection peaks when probing a confined gas discharge in a discharge tube (confined plasma) with variable frequency

T.C. Killian, Nature 441, 297 (2006)

$$\int_{-r_f}^{r_f} k(r) dr = \pi j, \ j = 1, 2, 3, \dots$$

If to assume uniform distribution of electron density, then the dispersion relation reads as

$$\omega_j^2 = \omega_p^2 \left[1 + \left(\pi j \lambda_D / 2r_f \right)^2 \right]$$

At typical free electron density of $(2 - 6) \cdot 10^{20}$ cm⁻³ and electron energy of ~10 eV, $j \sim 10^3$. Taking into account actual plasma profile from simulations leads to $j \approx 120$. To obtain the grating periodicity of 200 nm c $E_e \sim 10$ eV, j = 54 but n_e must be close to n_{cr} :

$$\omega_j^2 - \omega_p^2 \approx 1.3 \times 10^{25} \,(\text{rad/s})^2$$

Plasma wave geometry in focusing region cross-section

1 μJ, 150 fs, NA = 0.25



Plasma waves: No tendency to form plane periodic structures

2. Nanoplasma self-ordering

V. R. Bhardwaj et al. PRL, 96, 057404 (2006)

Forest-fire model



Direction parallel to laser polarization



L.N. Gaier et al. J. Phys. B 37, L57 (2004)



The problems: 1. Idea of self-organization of nanoplasmas into nanoplanes is vague 2. Periodicity cannot not be explained

3. Exciton-mediated self-organization M. Beresna et al. APL, 101, 053120 (2012)



The Gross-Pitaevskii equation describes the ground state of a quantum system of identical bosons using the Hartree-Fock approximation and the pseudopotential interaction model



$$i\hbar \frac{\partial \Psi(\mathbf{r},t)}{\partial t} = \left(-\frac{\hbar^2}{2m}\nabla^2 + V(\mathbf{r}) + g|\Psi(\mathbf{r},t)|^2\right)\Psi(\mathbf{r},t).$$
$$\Psi(\mathbf{r}_1,\mathbf{r}_2,\ldots,\mathbf{r}_N) = \psi(\mathbf{r}_1)\psi(\mathbf{r}_2)\ldots\psi(\mathbf{r}_N)$$

Potential

Trial function

$$H = -\frac{\hbar^2}{2m}\frac{\partial^2}{\partial x^2} + \alpha |\psi|^2 \qquad \qquad \psi = \sqrt{\frac{N}{a}} \left(\frac{2}{\pi}\right)^{\frac{1}{4}} e^{-x^2/a^2}$$

Polarization along z to describe the longitudinal grating ∞

$$\mathbf{P}_{exc}(z,t) = \frac{1}{2\pi} \int_{-\infty}^{\infty} dz' g(z-z') \int_{-\infty}^{\infty} d\omega [\chi_e(\omega) \mathbf{E}(z',\omega) e^{-i\omega t}]$$

The problems:

- 1. Developed plasma screens weak dipole interaction between excitons
 - 2. What is the mean free path of excitons?

4. Ionization instability



Introducing perturbations:

$$\vec{E} = e_x [E_0 + u_1(r, t) + iv_1(r, t)] \exp[i\varphi_0(t) - ikz]$$

$$n_e = n_{e0} + n_{e1}$$

Searching solution in the form $u_1, v_1, n_1 \sim \exp(\Gamma t - i\kappa r)$

The dispersion relation $\Gamma[4\Gamma^{2} - (\kappa^{2}c^{2} - 4\omega^{2}\varepsilon_{0}\varepsilon\cos^{2}\alpha) - 8i\Gamma\omega\sqrt{\varepsilon_{0}\varepsilon}\cos\alpha)] = AW_{\rm MPI}\omega_{pm}^{2}(1 - \sin^{2}\alpha\cos^{2}\phi/(\varepsilon_{0}\varepsilon))$

 $A = d \ln W_{\rm MPI} / d \ln E$

E.S. Efimenko and A.V. Kim, Phys. Rev. E 84, 036408 (2011)



Self-organization of nanoplasma via volumetric Sipe's mechanism?



J.E. Sipe et al. Phys. Rev. B 27, 1141 (1983)



D. Duft et al. J. Appl. Phys. 105, 034908 (2009)



M. Hörstmann-Jungemann et al. J. Laser Micro/Nanoeng. 4, 135 (2009)



Interacting dipoles



Volumetric FDTD simulations?

J.Z.P. Skolski et al. Phys. Rev. B 85, 075320 (2012)



034908 (2009)

In volumetric case refractive index change is governed by several processes that complicates theoretical consideration: $\Delta n = \Delta n_{Drude} + \Delta n_{Kerr} + \Delta n_{trap} + \Delta n_{th} + \Delta n_{P} + \Delta n_{\rho}$

Further details:

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Plausible explanation of pulse front tilt effect; Material properties favorable for nanograting imprinting

Conclusion

Deep understanding of interaction of ultrashort laser pulses with bulk transparent materials is an extremely complicated phenomenon which requires consolidating knowledge of optics, solid state physics and chemistry, plasma physics, thermodynamics, theory of elasticity and plasticity.

The numerical modeling is an important supplement of experimental studies. It may be used as a very helpful tool to predict and foresee the underlying physics of phenomenon. Many detailed aspects which can be overlooked in experiments may be revealed by numerical modeling.



"Physics lesson" by Sergei Korsun



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Thank you for attention!

